Schottky Barrier Diode

DB4J406K0R

Unit: mm

0.13

DB4J406K0R

Panasonic

Silicon epitaxial planar type

For high speed switching circuits

- Features
- · Small reverse current IR
- · Short reverse recovery time trr
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: 4B
- Basic Part Number : Dual DB2J406 (Parallel)
- Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

0.65 (0.65)
1.3

1. Anode1 3. Cathode2
2. Anode2 4. Cathode1

Panasonic SMini4-F3-B
JEITA SC-113BB
Code —

2.1

2.0

0.3

■ Absolute Maximum Ratings Ta = 25 °C

Parameter		Symbol	Rating	Unit
Reverse voltage		VR	40	V
Repetitive peak reverse voltage		VRRM	40	V
Forward current	Singie	IF	100	mA
	Doubie *1	1 1	75	mA
Peak forward current	Single	IFM	300	mA
	Doubie *1	II-IVI	225	mA
Non-repetitive peak	Single	IFSM	1	Α
forward surge current *2	Doubie *1	II SIVI	0.75	Α
Junction temperature		Tj	125	°C
Operating ambient temperature		Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +125	°C	
Note: *1 Value of each diode	in double used			

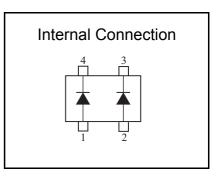


Established: 2010-03-24

: 2013-12-13

Revised

^{*2} The peak-to-peak value in one cycle of 50 Hz sine wave (non-repetitive)



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■ Electrical Characteristics Ta = 25 °C ± 3 °C									
Parameter	Symbol	Conditions	Min	Тур	Max	Unit			
Forward voltage	VF	IF = 100 mA			0.6	V			
Reverse current	IR	VR = 40 V			5	μA			
Terminal capacitance	Ct	VR = 10 V, f = 1 MHz		2.2		pF			
Reverse recovery time *1	trr	IF = IR = 100 mA, Irr = 10 mA RL = 100 Ω		0.9		ns			

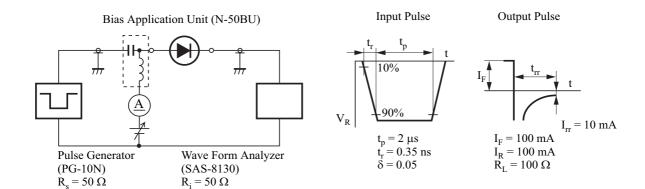
Note: 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

- 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
- 3. Absolute frequency of input and output is 250 MHz.
- 4. *1 trr test circuit

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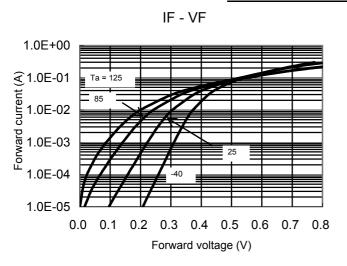
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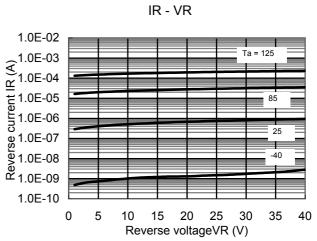
Revision. 2

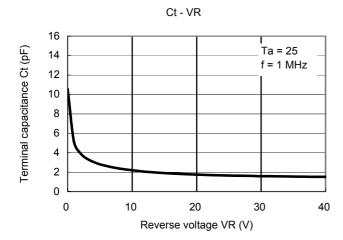
Schottky Barrier Diode

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Technical Data (reference)







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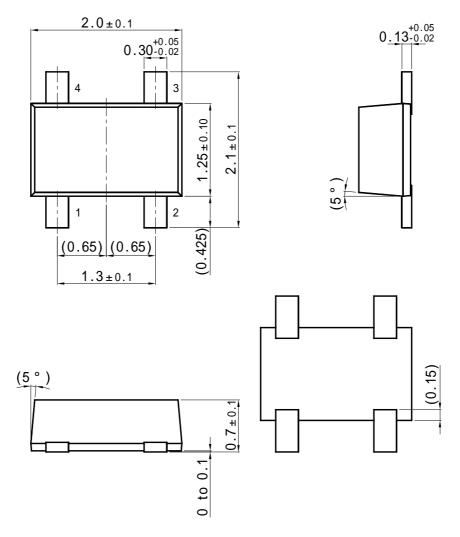
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DB4J406K0R

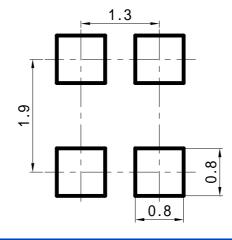
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SMini4-F3-B

Unit: mm



■ Land Pattern (Reference) (Unit: mm)



Established: 2010-03-24 Revised: 2013-12-13

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